Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.350 inches and 0.370 inches

Overall Diameter:

Between 0.210 inches and 0.230 inches

Mounting Facility Quantity:

2

Mounting Method:

Bracket and unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

87.5 regulator voltage

Current Rating Per Characteristic:

200.00 microamperes repetitive peak forward current

Power Rating Per Characteristic:

150.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Terminal Type And Quantity:

2 uninsulated wire lead

Specification Data:

80131-release2013 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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